

BAT48

FEATURES :

- For general purpose applications
- These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- This diode is also available in the Mini-MELF case with type designations LL48
- Pb / RoHS Free

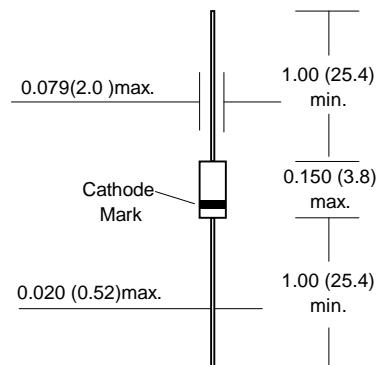
MECHANICAL DATA :

Case: DO-35 Glass Case

Weight: approx. 0.13g

SCHOTTKY BARRIER DIODE

DO - 35 Glass
(DO-204AH)



Dimensions in inches and (millimeters)

Maximum Ratings and Thermal Characteristics

(Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	40	V
Continuous Forward Current	I _F	350 ⁽¹⁾	mA
Repetitive Peak Forward Current at tp < 1s,	I _{FRM}	1 ⁽¹⁾	A
Forward Surge Current at tp < 10 ms,	I _{FSM}	7.5 ⁽¹⁾	A
Power Dissipation ,Ta = 65 °C	P _D	330 ⁽¹⁾	mW
Thermal Resistance Junction to Ambient Air	R _{θJA}	300 ⁽¹⁾	°C/W
Junction Temperature	T _J	125	°C
Ambient Operating Temperature Range	T _a	-65 to + 125	°C
Storage temperature range	T _s	-65 to + 150	°C

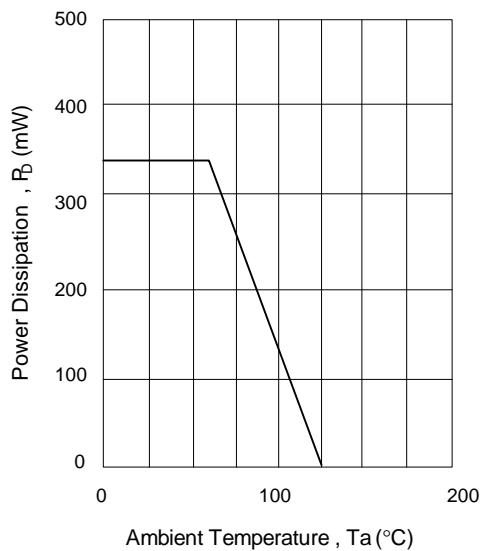
Note: (1) Valid provided that leads at a distance of 4mm from case are kept at ambient temperature.

Electrical Characteristics (T_J = 25°C unless otherwise noted)

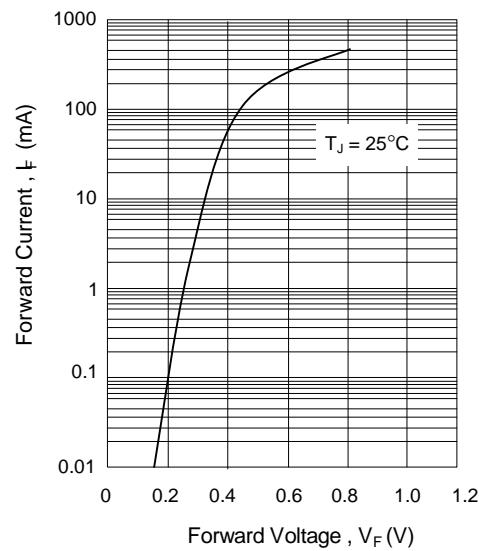
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V _{(BR)R}	I _R = 100 μA (pulsed)	40	-	-	V
Reverse Current	I _R	V _R = 10 V	-	-	2	
Pulse Test tp <300μs , δ <2%		V _R = 20 V	-	-	5	μA
		V _R = 40 V	-	-	25	
Forward Voltage	V _F	I _F = 1mA	-	-	0.30	
Pulse Test tp <300μs , δ <2%		I _F = 10mA	-	-	0.40	V
		I _F = 30mA	-	-	0.50	
		I _F = 100mA	-	-	0.75	
		I _F = 500mA	-	-	0.90	
Diode Capacitance	C _d	V _R = 1V, f = 1MHz	-	12	-	pF

RATING AND CHARACTERISTIC CURVES (BAT48)

Admissible Power Dissipation
vs. Ambient Temperature



Typical Forward Characteristics



Typical Reverse Characteristics

